

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Reflective Object Sensor

OPB702, OPB702D, OPB702R, OPB702RR



Features:

- Focused for maximum sensitivity
- Choice of phototransistor, photodarlington or base-emitter resistor
- · Low cost plastic housing



Description:

The **OPB702** series consists of an infrared Light Emitting Diode (LED) or red Visible Light Emitting Diode (VLED) and the choice of a NPN silicon phototransistor **(OPB702)**, a photodarlington **(OPB702D)** or a base-emitter resistor for low light suppression **(OPB702R, OPB702RR)**.

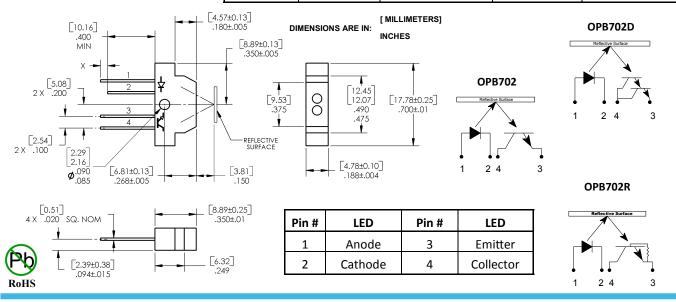
On each sensor, the LED and the phototransistor, photodarlington or base-emitter resistor are mounted side-by-side on converging optical axes in a black plastic housing. The **OPB702** uses type OP505 sensor, the **OPB702D** uses an OP535 sensor and the **OPB702R**, **OPR702RR** uses an OP705 sensor.

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- · Machine safety
- End of travel sensor
- Door sensor

Ordering Information									
Part Number	LED Peak Wavelength	Sensor	Reflection Distance Inch (mm)	Lead Length / Spacing					
OPB702		Transistor		0.400" / 0.100"					
OPB702D	890 nm	Darlington	0.150"						
OPB702R		Transistor and Rbe	(3.81mm)						
OPB702RR	640 nm	Transistor and Rbe							



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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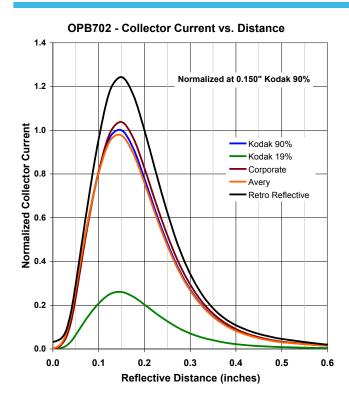


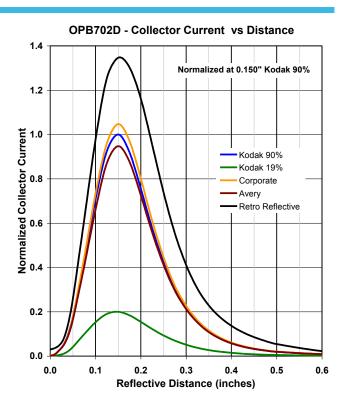
Absolut	e Maximum Ratings (T _A = 25° C unle	ss other	wise no	ted)			
Stora	-40° C to +85° C						
Lead	260° C						
Input Dio	de						
Peak	Forward Current						50 mA
Reverse Voltage							2 \
Power Dissipation] ⁽¹⁾							100 mW
Output P	hotosensor						
Collec	30 \ 15 \						
Emitter-Collector Voltage							5 \
Powe	er Dissipation] ⁽¹⁾						100 mW
Electrico	al Characteristics (T _A = 25° C unless o	therwise	noted))			
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS	
Input Dio	de (see OP265 or OP165 for Infrared LED & 0	OVLAS6CI	38 for Re	d LED fo	or additio	nal information)	
V _F	Forward Voltage (Infrared LED) Red (VLED)	-	-	1.7 2.4	V	I _F = 20 mA I _F = 40 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V	
Output P	hototransistor (see OP505 for Phototransis	tor, OP70)5 for Rb	e-Photo	transisto	r, OP535 for Photodarl	ington)
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage OPB702 OPB702D OPB702R, OPB702RR	30 15 30	- - -	- - -	v	$I_C = 100 \mu A, I_F = 0, E_e = 0$ $I_C = 1 mA, I_F = 0, E_e = 0$ $I_C = 1 mA, I_F = 0, E_e = 0$	
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage OPB702 OPB702D	5 5	-		V	$I_E = 100 \mu A$, $I_F = 0$, $E_E = 0$ $I_E = 100 \mu A$, $I_F = 0$, $E_E = 0$	
I _{ECO}	Emitter-Reverse Current OPB702R, OPB702RR	-	-	100	μА	$V_{CE} = 0.4 \text{ V}, I_F = 0, E_E = 0$	
I _{CEO}	Collector Dark Current OPB702 OPB702D OPB702R, OPB702RR	- - -		100 250 100	nA nA nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0 \\ V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0 \\ V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$	
Combine	d						
V _{CE(SAT)} ⁽³⁾	Collector-Emitter Saturation Voltage OPB702 OPB702D OPB702R, OPB702RR	- - -	- - -	0.4 1.1 0.4	V V V	I_F = 40 mA, I_C = 250 μ A, d = .15" (3.81 mm) I_F = 40 mA, I_C = 400 μ A, d = .15" (3.81 mm) I_F = 40 mA, I_C = 250 μ A, d = .15" (3.81 mm)	
I _{C(ON)} (3)(4)	On-State Collector Current OPB702 OPB702D OPB702R OPB702RR	0.1 3.2 0.4 0.2	- - - -	1.0 65.0 6.0 3.5	mA	I _F = 40 mA, V _{CE} = 5 V, d = .15" (3.81 mm)	

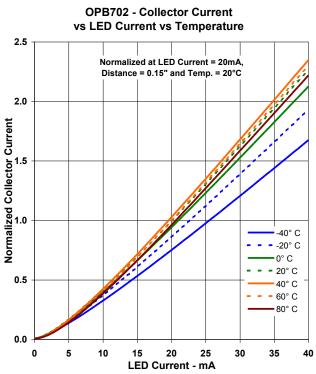
Reflective Object Sensor

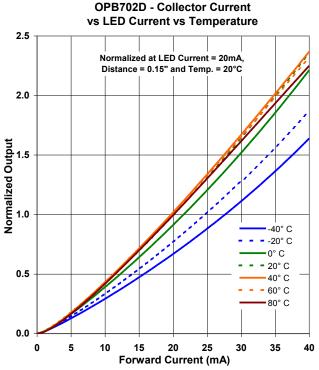
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